

MDLF147-X REV 0A1

Original Creation Date: 02/08/95

Last Update Date: 08/24/98

Last Major Revision Date: 02/08/95

WIDE BANDWIDTH QUAD JFET INPUT OPERATIONAL AMPLIFIER

General Description

The LF147 is a low cost, high speed quad JFET input operational amplifier with an internally trimmed input offset voltage (BI-FET II[™] technology). The device requires a low supply current and yet maintains a large gain bandwidth product and a fast slew rate. In addition, well matched high voltage JFET input devices provide very low input bias and offset currents. The LF147 is pin compatible with the standard LM148. This feature allows designers to immediately upgrade the overall performance of existing LF148 and LM124 designs.

The LF147 may be used in applications such as high speed integrators, fast D/A converters, sample-and-hold circuits and many other circuits requiring low input offset voltage, low input bias current, high input impedance, high slew rate and wide bandwidth. The device has low noise and offset voltage drift.

Industry Part Number

LF147

NS Part Numbers

LF147J-SMD

Prime Die

LF147

Controlling Document

8102306CA

Processing

MIL-STD-883, Method 5004

Quality Conformance Inspection

MIL-STD-883, Method 5005

Subgrp	Description	Temp (°C)
1	Static tests at	+25
2	Static tests at	+125
3	Static tests at	-55
4	Dynamic tests at	+25
5	Dynamic tests at	+125
6	Dynamic tests at	-55
7	Functional tests at	+25
8A	Functional tests at	+125
8B	Functional tests at	-55
9	Switching tests at	+25
10	Switching tests at	+125
11	Switching tests at	-55

Features

- | | |
|--|---------------------|
| - Internally trimmed offset voltage | 5mV Max |
| - Low input bias current | 50pA Typ |
| - Low input noise current | 0.01 pA/Root Hz Typ |
| - Wide gain bandwidth | 4MHz Typ |
| - High slew rate | 13V/uS Typ |
| - Low supply current | 7.2mA Typ |
| - High input impedance | 10E12 Ohms Typ |
| - Low total harmonic distortion $A_v=10$,
RL = 10K, Vo = 20Vp-p, BW = 20Hz - 20KHz | <0.02% Typ |
| - Low 1/f noise corner | 50Hz Typ |
| - Fast settling time to 0.01% | 2uS Typ |

(Absolute Maximum Ratings)

Supply Voltage	+22V
Differential Input Voltage	±38V
Input Voltage Range (Note 1)	±19V
Output Short Circuit Duration (Note 2)	Continuous
Power Dissipation (Note 3, 4)	900mW
Tj Max	150 C
ThetaJa Ceramic DIP (J) Package	70 C/W
Operating Temperature Range	-55 C ≤ Ta ≤ 125 C
Storage Temperature Range	-65 C ≤ Ta ≤ 150 C
Lead Temperature (Soldering, 10 seconds)	260 C
Soldering Information Dual-In-Line Package (Soldering, 10 seconds)	260 C
ESD Tolerance (Note 5)	900V

Note 1: Unless otherwise specified the absolute maximum negative input voltage is equal to the negative power supply voltage.

Note 2: Any of the amplifier outputs can be shorted to ground indefinitely, however, more than one should not be simultaneously shorted as the maximum junction temperature will be exceeded.

Note 3: For operating at elevated temperature, these devices must be derated based on a thermal resistance of ThetaJa.

Note 4: Max. Power Dissipation is defined by the package characteristics. Operating the part near the Max. Power Dissipation may cause the part to operate outside guaranteed limits.

Note 5: Human body model, 1.5K Ohms in series with 100pF.

Electrical Characteristics

DC PARAMETERS

(The following conditions apply to all the following parameters, unless otherwise specified.)

DC: $V_s = \pm 15V$, $V_{cm} = 0V$, $R_s = 0$, $R_L = \text{Open}$

SYMBOL	PARAMETER	CONDITIONS	NOTES	PIN-NAME	MIN	MAX	UNIT	SUB-GROUPS
Vio	Input Offset Voltage	$V_{cc} = \pm 15V$			-9	9	mV	1
		$V_{cc} = \pm 15V$			-15	15	mV	2, 3
		$V_{cc} = \pm 9V$			-9	9	mV	1
Iio	Input Offset Current				-0.1	0.1	nA	1
					-20	20	nA	2
+Iib	Input Bias Current				-0.2	0.2	nA	1
					-50	50	nA	2
-Iib	Input Bias Current				-0.2	0.2	nA	1
					-50	50	nA	2
AVS	Large Signal Voltage Gain	$V_s = \pm 15V$, $V_o = 0$ to $+10V$, $R_L = 2K \text{ Ohms}$			35		V/mV	4
		$V_s = \pm 15V$, $V_o = 0$ to $+10V$, $R_L = 2K \text{ Ohms}$			15		V/mV	5, 6
		$V_s = \pm 15V$, $V_o = 0$ to $-10V$, $R_L = 2K \text{ Ohms}$			35		V/mV	4
		$V_s = \pm 15V$, $V_o = 0$ to $-10V$, $R_L = 2K \text{ Ohms}$			15		V/mV	5, 6
+Vo	Output Voltage Swing	$V_s = \pm 15V$, $R_L = 10K \text{ Ohms}$			12		V	4, 5, 6
		$V_s = \pm 15V$, $R_L = 2K \text{ Ohms}$			10		V	4, 5, 6
-Vo	Output Voltage Swing	$V_s = \pm 15V$, $R_L = 10K \text{ Ohms}$				-12	V	4, 5, 6
		$V_s = \pm 15V$, $R_L = 2K \text{ Ohms}$				-10	V	4, 5, 6
VCM	Input Common Mode Voltage Range		1		± 11		V	1, 2, 3
CMRR	Common Mode Rejection Ratio	$V_{cm} = \pm 11V$			80		dB	1
+PSRR	Power Supply Rejection Ratio	$+V_s = 15$ to $9V$, $-V_s = -15V$			80		dB	1
-PSRR	Power Supply Rejection Ratio	$+V_s = 15V$, $-V_s = -15$ to $-9V$			80		dB	1
+Is	Supply Current					14	mA	1
-Is	Supply Current				-14		mA	1
+Ios	Output Short Circuit Current	$V_s = \pm 15V$			-57	-13	mA	1, 3
		$V_s = \pm 15V$			-40	-6	mA	2
-Ios	Output Short Circuit Current	$V_s = \pm 15V$			13	57	mA	1, 3
		$V_s = \pm 15V$			6	40	mA	2

Electrical Characteristics

AC PARAMETERS

(The following conditions apply to all the following parameters, unless otherwise specified.)

DC: $V_s = \pm 15V$, $V_{cm} = 0V$, $R_s = 0$, $R_L = \text{Open}$

SYMBOL	PARAMETER	CONDITIONS	NOTES	PIN-NAME	MIN	MAX	UNIT	SUB-GROUPS
+Sr	Slew Rate	$V_{in} = -5V \text{ to } +5V$, $A_V = 1$			8		V/ μ S	7
					5		V/ μ S	8A, 8B
-Sr	Slew Rate	$V_{in} = +5V \text{ to } -5V$, $A_V = 1$			8		V/ μ S	7
					5		V/ μ S	8A, 8B

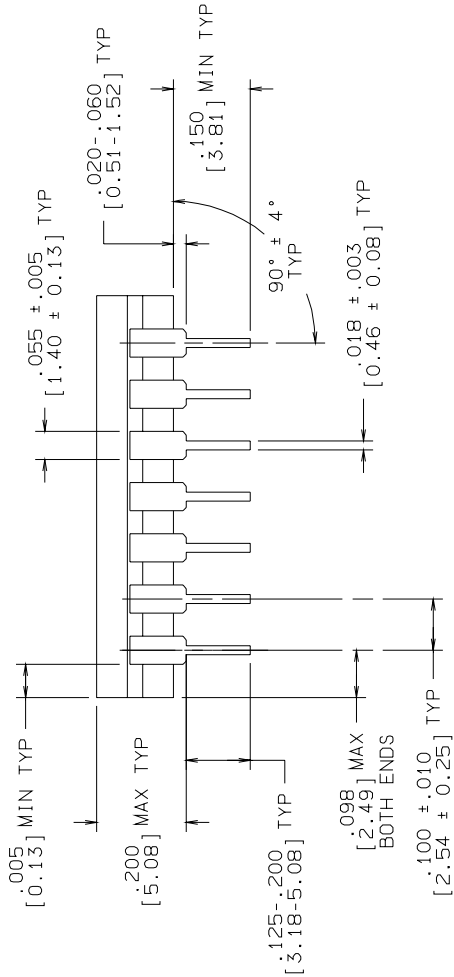
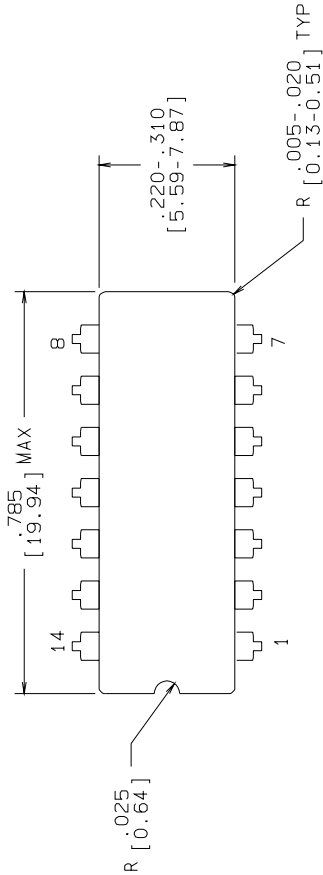
Note 1: Parameter tested go-no-go only.

Graphics and Diagrams

GRAPHICS#	DESCRIPTION
09173HRA2	CERDIP (J), 14 LEAD (B/I CKT)
J14ARH	CERDIP (J), 14 LEAD (P/P DWG)
P000193A	CERDIP (J), 14 LEAD (PINOUT)

See attached graphics following this page.

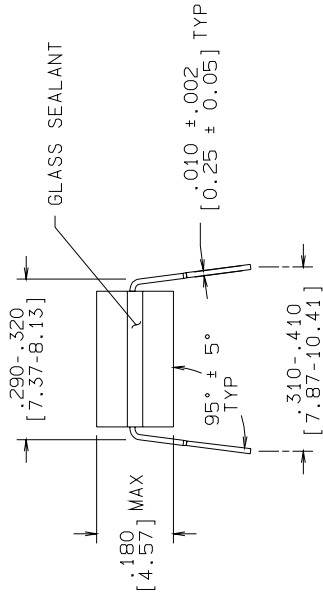
R E V I S I O N S				
LTR	DESCRIPTION	E.C.N.	DATE	BY/APP'D
H	REVISE PER CURRENT STD; REDRAW	10001	09/15/93	TL/



CONTROLLING DIMENSION: INCH

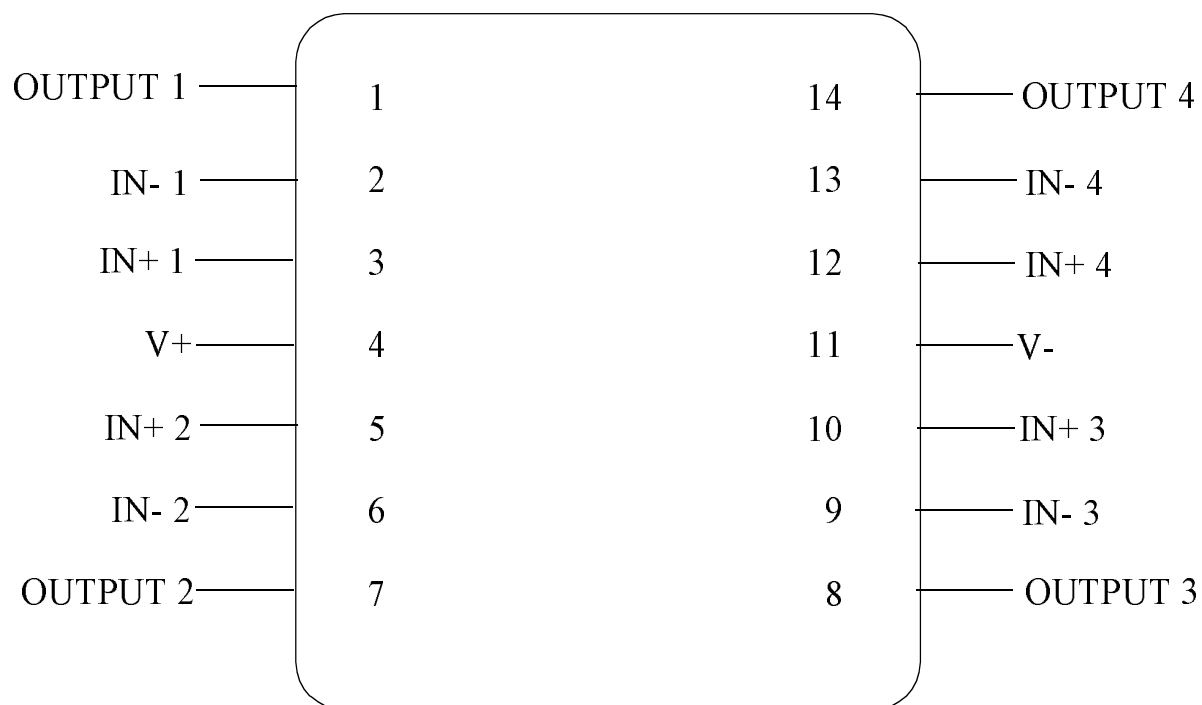
NOTES: UNLESS OTHERWISE SPECIFIED

1. LEAD FINISH TO BE 200 MICROMETERS / 5.08 MICROMETERS MINIMUM SOLDER MEASURED AT THE CREST OF THE MAJOR FLATS.
2. JEDEC REGISTRATION MO-036, VARIATION AB, DATED 04/1981.



MIL/AERO MIL-M-38510
CONFIGURATION CONTROL CONFIGURATION CONTROL

APPROVALS	DATE	NATIONAL SEMICONDUCTOR CORPORATION		
DRAWN LEQUANG	09/15/93	2900 Semiconductor Drive, Santa Clara, CA 95052-8090		
DFTG. CHK.				
ENGR. CHK.				
APPROVAL		CERDIP (J) , 14 LEAD,		
 PROJECTION INCH [MM]	SCALE	SIZE	DRAWING NUMBER	REV
	N/A	B	MKT-J14A	H
DO NOT SCALE DRAWING		SHEET	1	OF 1



LF147J
14 - LEAD DIP
CONNECTION DIAGRAM
TOP VIEW
P000193A



National Semiconductor™
 MIL/AEROSPACE OPERATIONS
 2900 SEMICONDUCTOR DRIVE
 SANTA CLARA, CA 95050

Revision History

Rev	ECN #	Rel Date	Originator	Changes
0A1	M0003009	08/24/98	Rose Malone	Update MDS: MDLF147-X Rev. 0A0 to MDLF147-X Rev. 0B1. Updated Burn-In graphic and added Pinout. Changed NSID to reflect SMD per Spec Control.